



MEMS Test Structures for Residual Stress Measurements

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Outline



- Motivation
- Theory
- Results and Discussions
- Summary
- References



MEMS Test structures*

- **Displacement Type: T, H shape structure**
- **Buckling Type: Beams, Cantilevers, Gückel Rings, Diamond structure**
- **Rotation Type : Pointers, Bent-beam, Lancet structures**

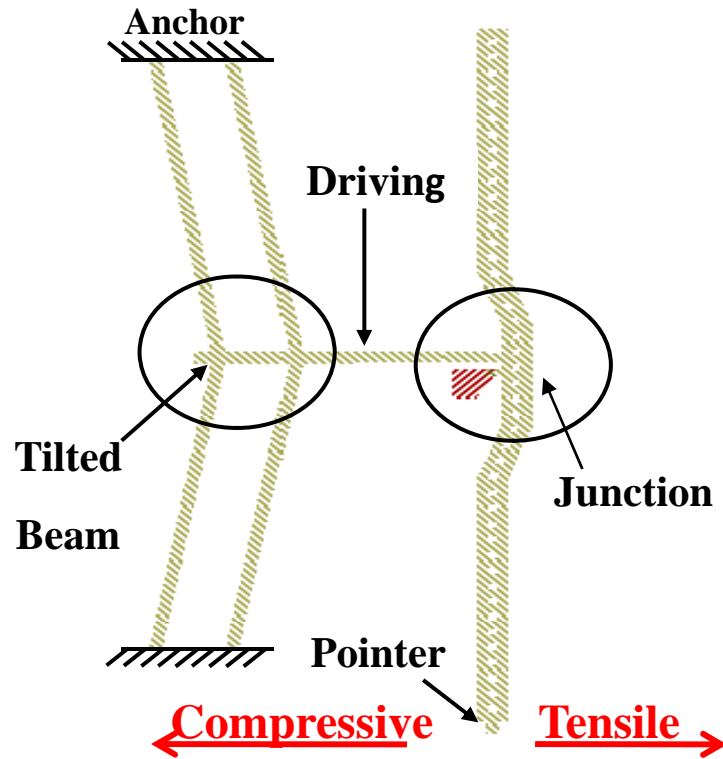
Residual Stresses

* B.P. van Driehuisen, J.F.L. Goosen, P.J. French, Comparison of techniques for measuring both compressive and tensile stress in thin films, Sens. Actuators A. 37/38, 756–765 (1993).
Q. He, Z.X. Luo, X.Y. Chen ,Comparison of residual stress measurement in thin films using surface micromachining method, Thin Solid Films 516, 5318–5323 (2008).

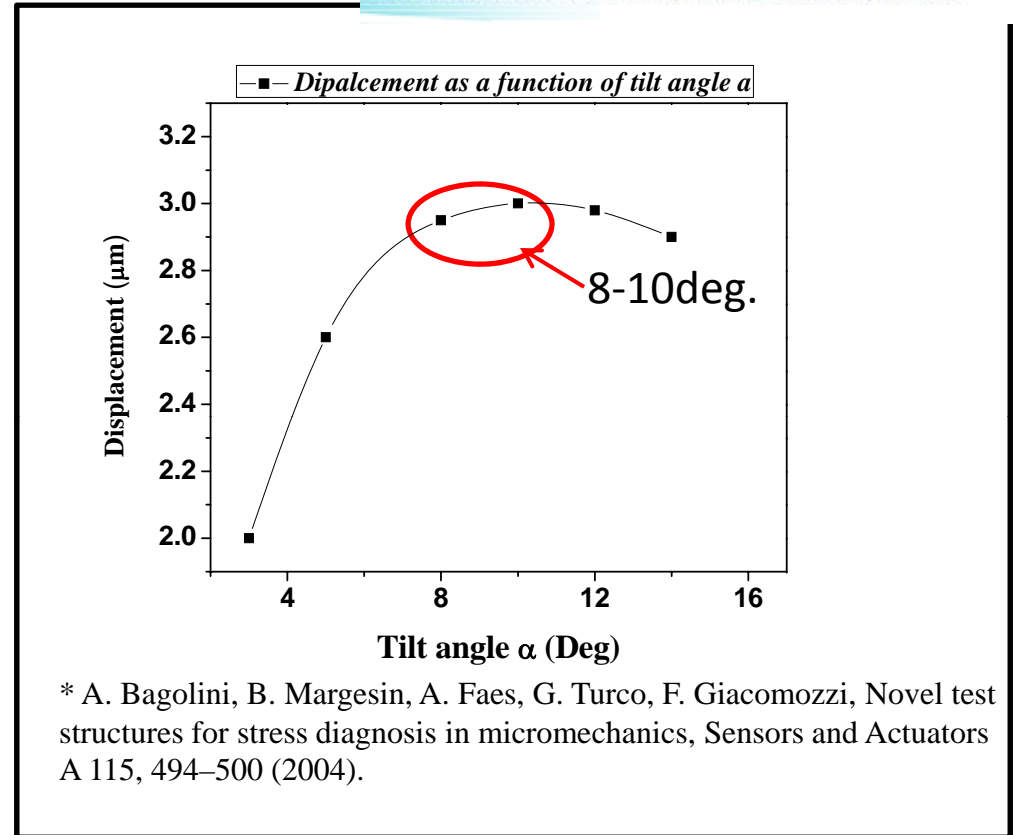




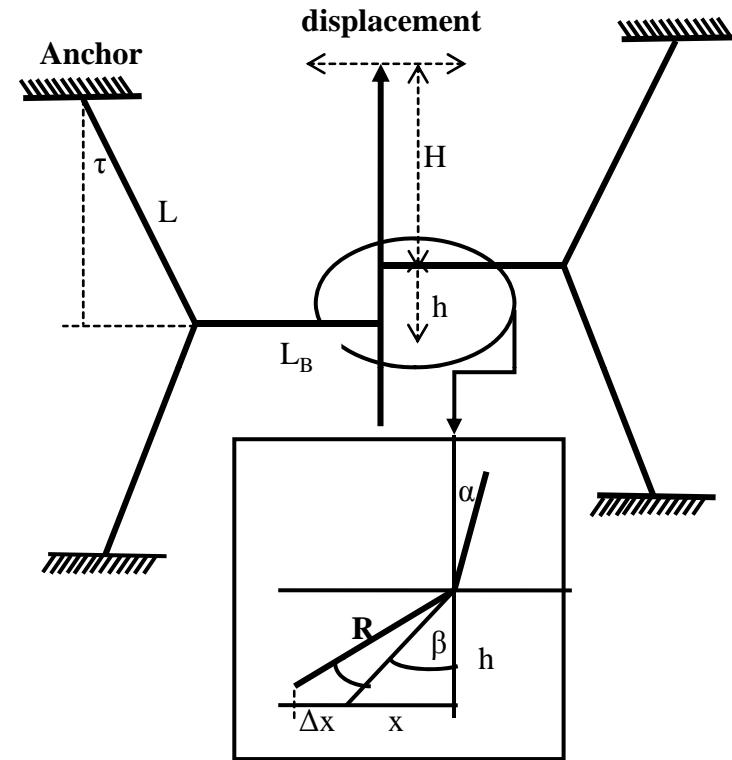
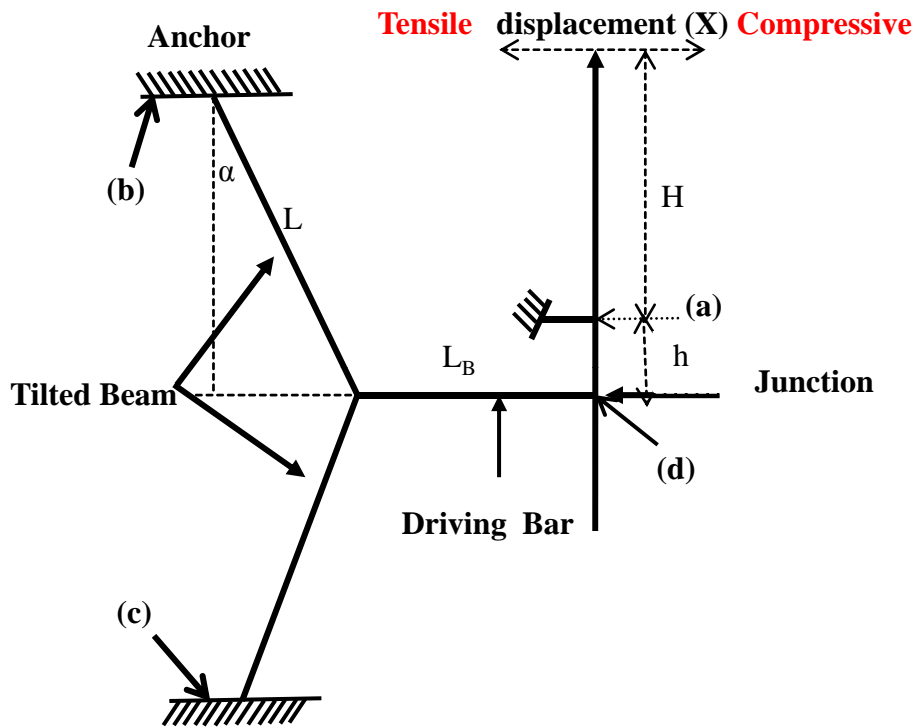
Theory



Basic Layout of Lancet



Schematic of modeling sequence



A. Conceptual schematic of the asymmetric lancet

B. Conceptual schematic of the symmetric lancet

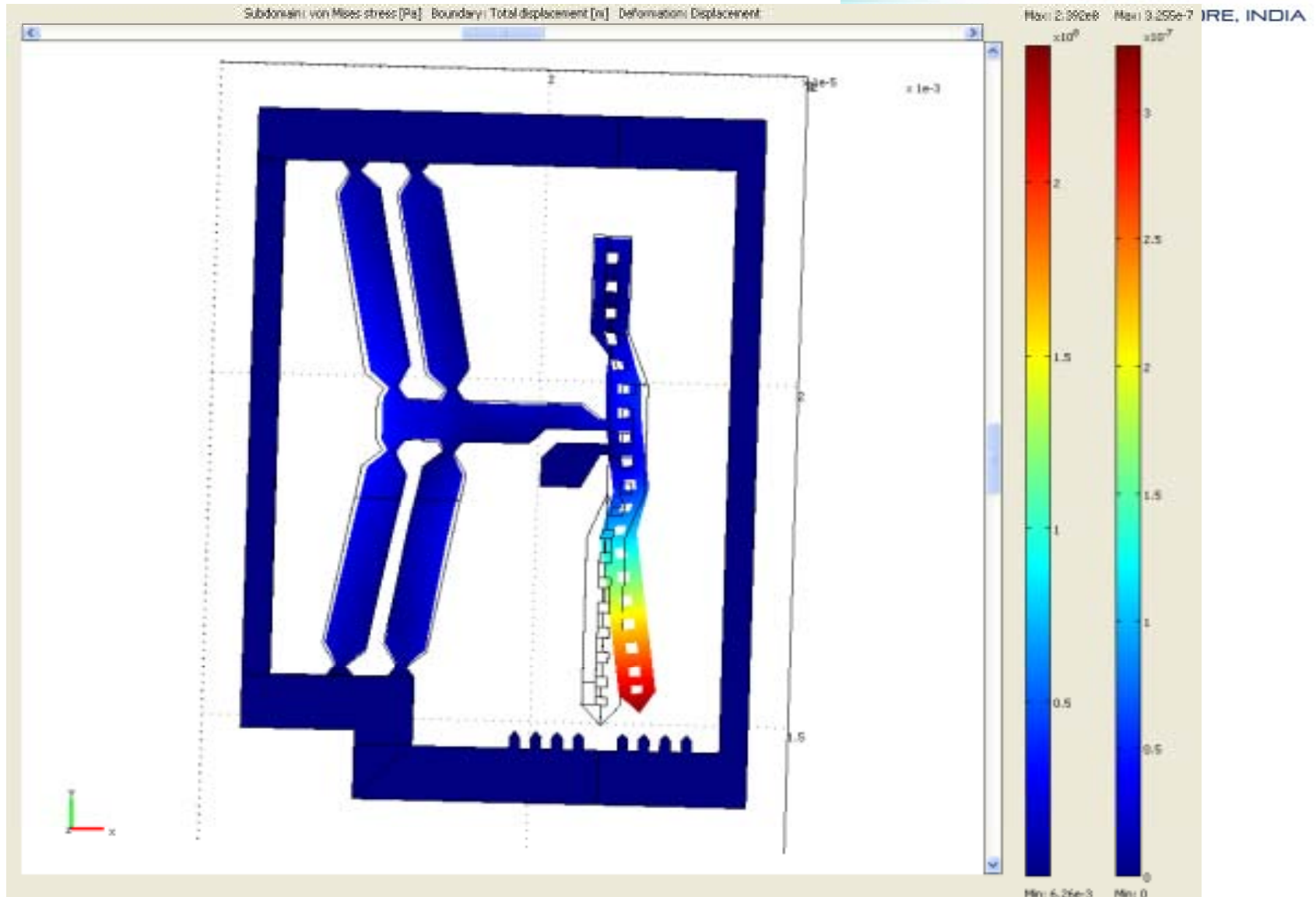
$$\text{displacement } X = \frac{H}{h} \left\{ \Delta L_B + (L + \Delta L) \times \sin \left[\arccos \left(\frac{L \cos \alpha}{L + \Delta L} \right) \right] - L \sin \alpha \right\}$$

$$\text{displacement} = H \sin \alpha = H \sin \left[\arcsin \left[\frac{x + \left\{ \Delta L_B + (L + \Delta L) \times \sin \left[\arccos \left(\frac{L \cos \tau}{L + \Delta L} \right) \right] - L \sin \tau \right\}}{h / \sin \beta} \right] - \beta \right]$$



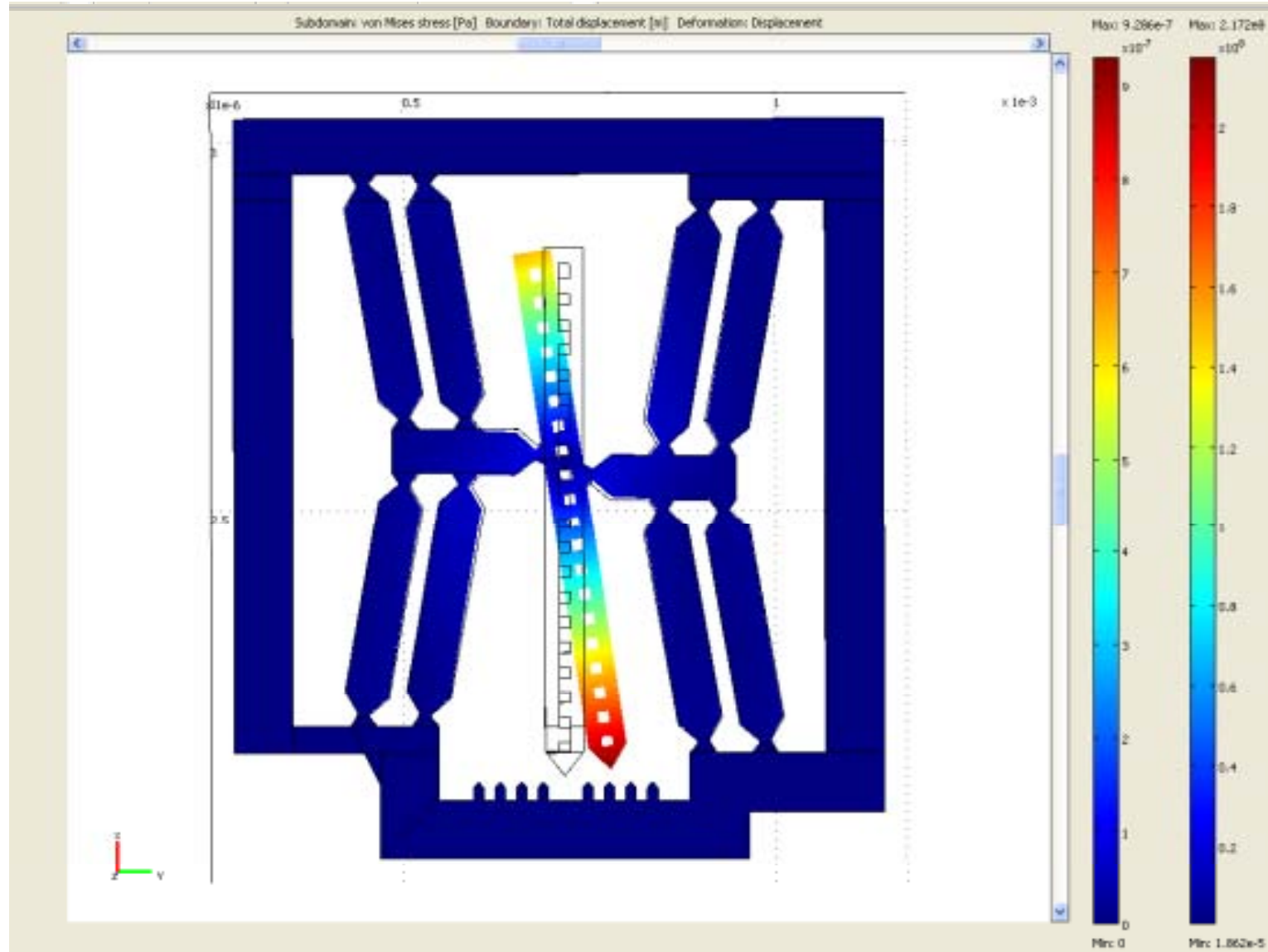
Results and Observations

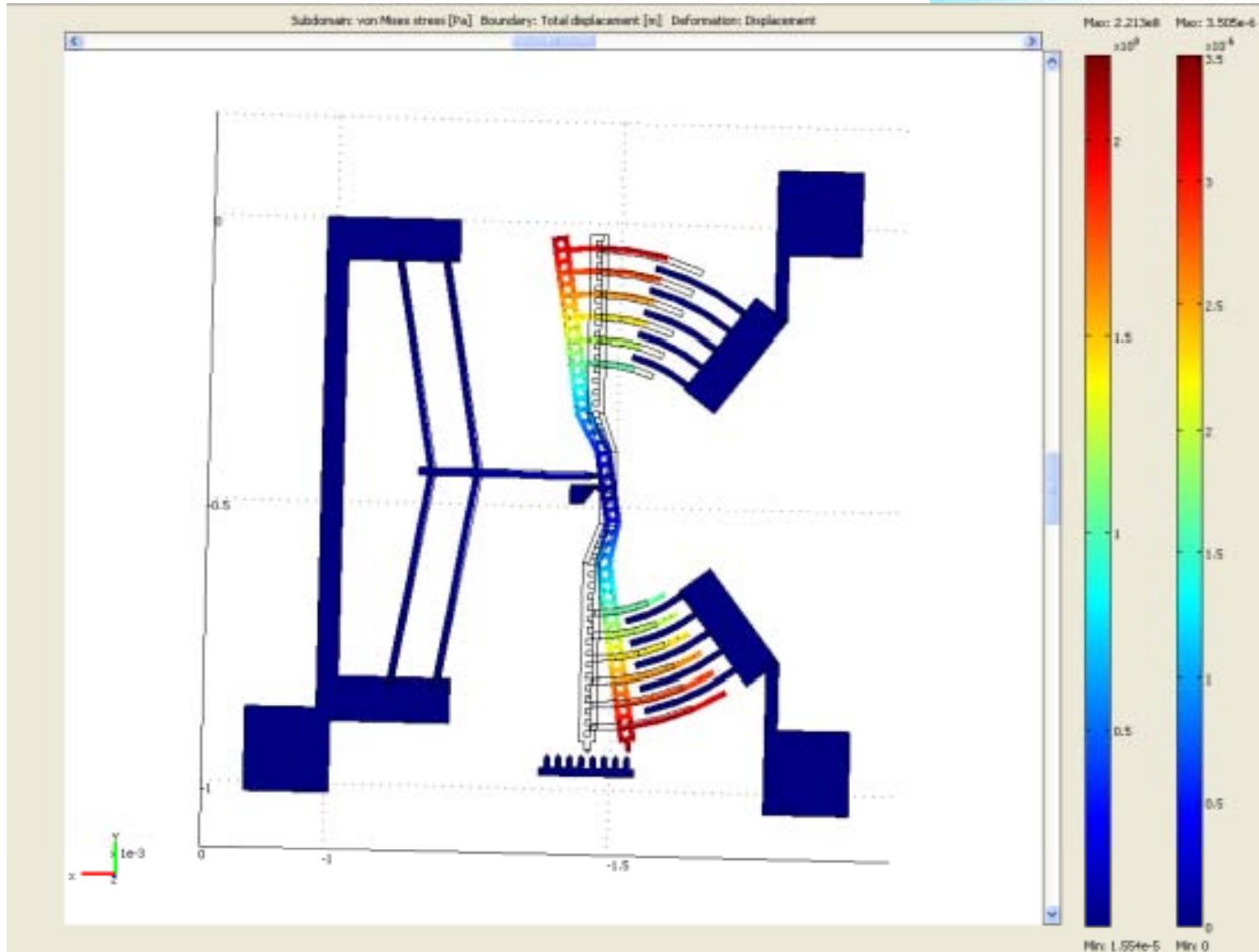
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Asymmetric pointer structure with single junction layout

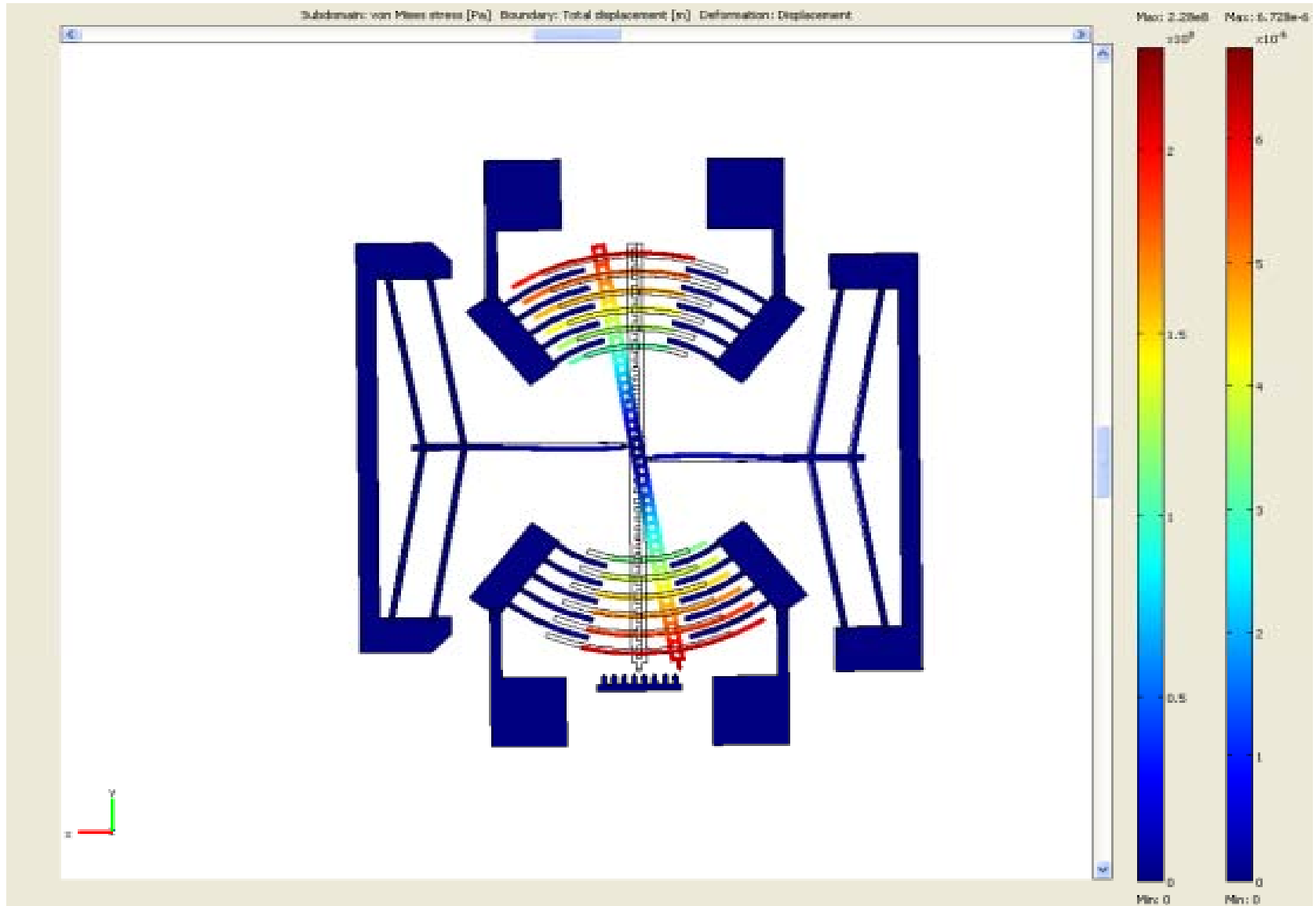
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Cont...



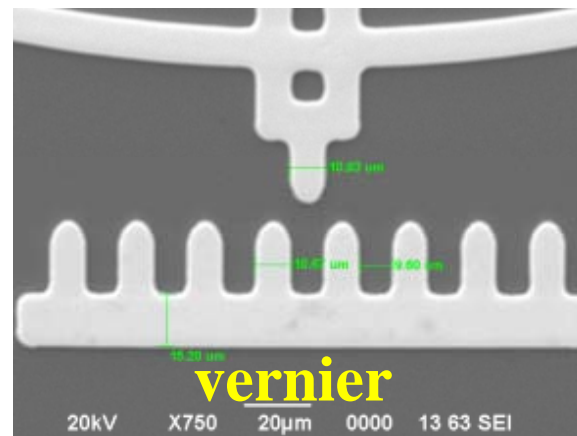
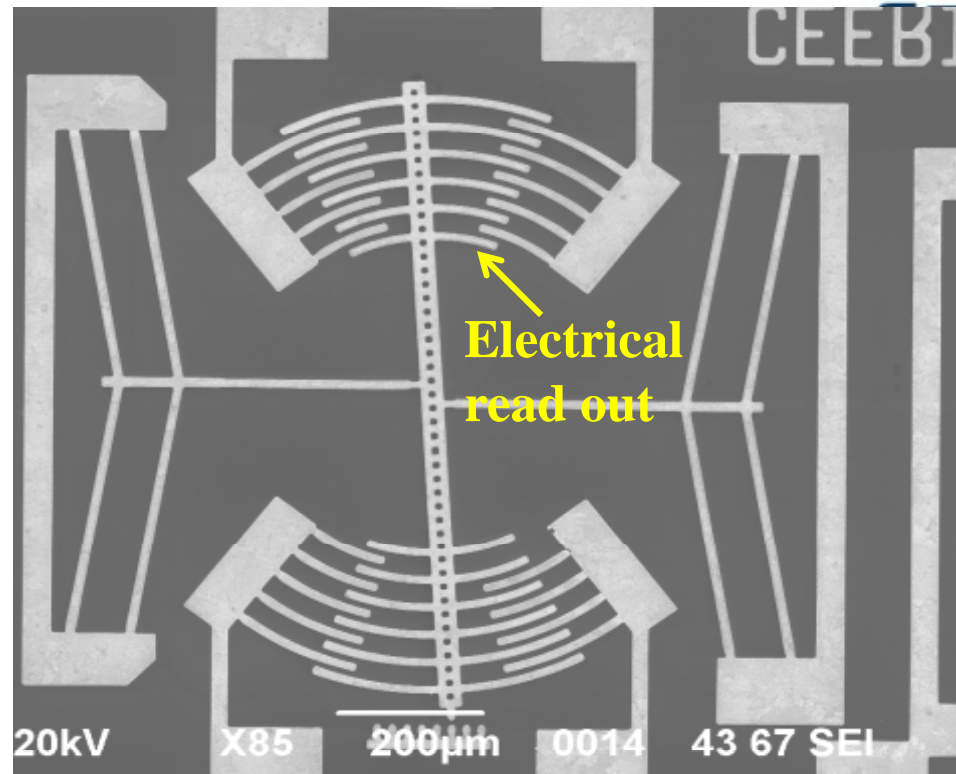


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Asymmetric Lancet pointer structure with single junction and electrical read out Cont...



Symmetric Lancet pointer structure with double junction and electrical read out



SEM image of fabricated symmetric lancet



Summary

Type Structures	Displacement (μm)	Stress (MPa)	Stress Type
Asymmetric Pointer	0.3	239	Tensile
Symmetric Pointer	0.9	217	Tensile
Asymmetric Lancet Pointer	3.5	221	Tensile
Symmetric Lancet Pointer	6.7	228	Tensile



References

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- [2] L. Elbrecht, U. Storm, R. Catanescu, Comparison of stress measurement techniques in surface micromachining, *J. Micromech. Microeng.* 7 , 151–154 (1997) .
- [3] B. Yogesh, K. Najafi, Gianchandani, Bent beam strain sensors, *J. Microelectromech. Syst.* 5 (1) , 52–58 (1996).
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- [5] A. Bagolini, B. Margesin, A. Faes, G. Turco, F. Giacomozzi, Novel test structures for stress diagnosis in micromechanics, *Sensors and Actuators A* 115, 494–500 (2004).
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Thank You!